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CCS K 46

JB

**INDUSTRY STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

JB/T 8951.2-2025

Replacing JB/T 8951.2-1999

**Insulated gate bipolar transistor (IGBT) - Part 2: Arm Module
(English Translation)**

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What this standard covers

This standard specifies the model, dimensions, ratings, characteristics, inspection rules, quality assessment categories, marking, packaging, storage, and order forms for insulated gate bipolar transistor (IGBT) arm modules. This standard applies to the manufacture of industrial-grade general-purpose IGBT arm modules with a collector DC current not exceeding 1200A and a collector-emitter voltage not exceeding 1700V.

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